

### LD2980ABxx LD2980Cxx

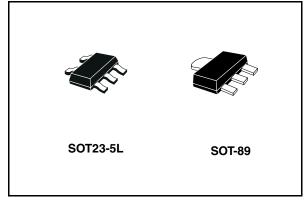
# Ultra low drop voltage regulators compatible with low ESR inhibit output capacitors

#### **Features**

- Stable with low ESR ceramic capacitors
- Ultra low dropout voltage (0.12 V typ. at 50 mA load, 7 mV typ. at 1 mA load)
- Very low quiescent current (80 μA typ. at no load in on mode; max 1 μA in off mode)
- Guaranteed output current up to 50 mA
- Logic-controlled electronic shutdown
- Output voltage of 1.8; 2.5; 3.0; 3.3; 3.6; 5.0 V
- Internal current and thermal limit
- ± 0.5% Tolerance output voltage available (A version)
- Output low noise voltage 160 µVRMS
- Temperature range: -40 to 125 °C
- Smallest package SOT23-5L and SOT-89
- Fast dynamic response to line and load changes

#### **Description**

The low drop-voltage and the ultra low quiescent current make them suitable for low noise, low power applications and in battery powered



systems. The quiescent current in sleep mode is less than 1  $\mu$ A when the INHIBIT pin is pulled low. A shutdown logic control function is available on pin n° 3 (TTL compatible). This means that when the device is used as local regulator, it is possible to put a part of the board in standby, decreasing the total power consumption. The LD2980 is designed to work with low ESR ceramic capacitors. Typical applications are cellular phone, laptop computer, personal digital assistant (PDA), personal stereo, camcorder and camera.

Table 1. Device summary

Order codes								
AB V	ersion	C Ve	rsion	Output valtage				
SOT23-5L	SOT-89	SOT23-5L SOT-89		Output voltage				
		LD2980CM18TR	LD2980CU18TR	1.8 V				
LD2980ABM25TR	LD2980ABU25TR (1)	LD2980CM25TR	LD2980CU25TR <sup>(1)</sup>	2.5 V				
LD2980ABM30TR	LD2980ABU30TR (1)	LD2980CM30TR <sup>(1)</sup>	LD2980CU30TR <sup>(1)</sup>	3.0 V				
LD2980ABM33TR	LD2980ABU33TR	LD2980CM33TR		3.3 V				
LD2980ABM36TR	LD2980ABU36TR (1)	LD2980CM36TR	LD2980CU36TR <sup>(1)</sup>	3.6 V				
LD2980ABM50TR	LD2980ABU50TR	LD2980CM50TR	LD2980CU50TR	5.0 V				

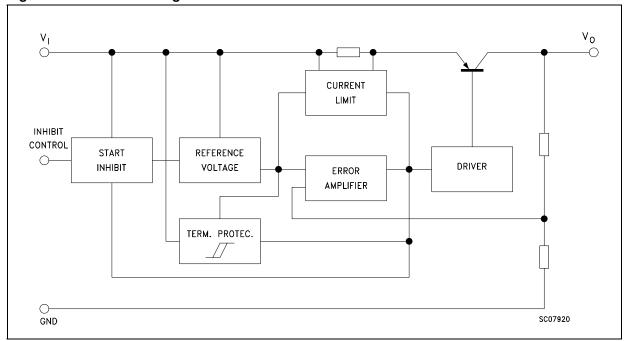
<sup>1.</sup> Available on request.

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### 1 Diagram

Figure 1. Schematic diagram



### 2 Pin configuration

Figure 2. Pin connections (top view)



Table 2. Pin description

	•		
Pin n° SOT23-5L	Pin n° SOT-89	Symbol	Name and Function
1	3	V <sub>IN</sub>	Input port
2	2	GND	Ground pin
3		INHIBIT	Control switch ON/OFF. Inhibit is not internally pulled-up; it cannot be left floating. Disable the device when connected to GND or to a positive voltage less than 0.18 V
4		NC	Not connected
5	1	V <sub>OUT</sub>	Output port

Table 3. Thermal data

Symbol	Parameter	SOT23-5L	SOT-89	Unit
R <sub>thJC</sub>	Thermal resistance junction-case	81	15	°C/W
R <sub>thJA</sub>	Thermal resistance junction-ambient	255	110	°C/W

### 3 Maximum ratings

Table 4. Absolute maximum ratings

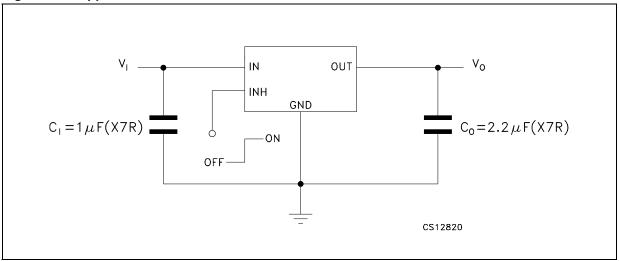
Symbol	Parameter	Value	Unit
VI	DC input voltage	-0.3 to 16	V
V <sub>INH</sub>	INHIBIT input voltage	-0.3 to 16	V
I <sub>O</sub>	Output current	Internally limited	
P <sub>D</sub>	Power dissipation	Internally limited	
T <sub>STG</sub>	Storage temperature range	-55 to 150	°C
T <sub>OP</sub>	Operating junction temperature range	-40 to 125	°C

Note:

Absolute maximum ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

### 4 Typical application

Figure 3. Application circuit



Note: Inhibit pin is not internally pulled-up then it must not be left floating. Disable the device when connected to GND or to a positive voltage less than 0.18 V.

### 5 Electrical characteristics

Table 5. Electrical characteristics for LD2980AB  $(T_J = 25 \, ^{\circ}C, \, V_I = V_{O(NOM)} + 1 \, V, \, C_I = 1 \, \mu F(X7R), \, C_O = 2.2 \, \mu F(X7R), \, I_O = 1 \, mA, \, V_{INH} = 2 \, V, \, unless \, otherwise \, specified).$ 

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit	
V <sub>OP</sub>	Operating input voltage		2.5		16	V	
		I <sub>O</sub> = 1 mA	2.487	2.5	2.513		
$V_{O}$	Output voltage	I <sub>O</sub> = 1 to 50 mA	2.481		2.519	V	
		$I_O = 1 \text{ to } 50 \text{ mA}, T_J = -40 \text{ to } 125^{\circ}\text{C}$	2.437		2.562		
		I <sub>O</sub> = 1 mA	2.835	2.85	2.864		
$V_{O}$	Output voltage	I <sub>O</sub> = 1 to 50 mA	2.828		2.871	V	
		$I_{O}$ = 1 to 50 mA, $T_{J}$ = -40 to 125°C	2.779		2.921		
		I <sub>O</sub> = 1 mA	2.985	3	3.015		
$V_{O}$	Output voltage	I <sub>O</sub> = 1 to 50 mA	2.978		3.023	V	
		$I_O = 1 \text{ to } 50 \text{ mA}, T_J = -40 \text{ to } 125^{\circ}\text{C}$	2.925		3.075		
		I <sub>O</sub> = 1 mA	3.184	3.2	3.216		
$V_{O}$	Output voltage	I <sub>O</sub> = 1 to 50 mA	3.176		3.224	V	
		$I_O = 1$ to 50 mA, $T_J = -40$ to 125°C	3.12		3.28		
		I <sub>O</sub> = 1 mA	3.284	3.3	3.317		
$V_{O}$	V <sub>O</sub> Output voltage	I <sub>O</sub> = 1 to 50 mA	3.275		3.325	V	
		$I_O = 1 \text{ to } 50 \text{ mA}, T_J = -40 \text{ to } 125^{\circ}\text{C}$	3.217		3.383		
			I <sub>O</sub> = 1 mA	3.582	3.6	3.618	
$V_{O}$	Output voltage	I <sub>O</sub> = 1 to 50 mA	3.573		3.627	V	
		$I_O = 1 \text{ to } 50 \text{ mA}, T_J = -40 \text{ to } 125^{\circ}\text{C}$	3.51		3.690		
		I <sub>O</sub> = 1 mA	3.781	3.8	3.819		
$V_{O}$	Output voltage	I <sub>O</sub> = 1 to 50 mA	3.772		3.829	V	
		$I_O = 1 \text{ to } 50 \text{ mA}, T_J = -40 \text{ to } 125^{\circ}\text{C}$	3.705		3.895		
		I <sub>O</sub> = 1 mA	3.98	4	4.02		
$V_{O}$	Output voltage	I <sub>O</sub> = 1 to 50 mA	3.97		4.03	V	
		$I_O = 1 \text{ to } 50 \text{ mA}, T_J = -40 \text{ to } 125^{\circ}\text{C}$	3.9		4.1		
		I <sub>O</sub> = 1 mA	4.677	4.7	4.724		
$V_{O}$	Output voltage	I <sub>O</sub> = 1 to 50 mA	4.665		4.735	V	
		$I_O = 1 \text{ to } 50 \text{ mA}, T_J = -40 \text{ to } 125^{\circ}\text{C}$	4.582		4.818		
		I <sub>O</sub> = 1 mA	4.826	4.85	4.874		
$V_{O}$	Output voltage	I <sub>O</sub> = 1 to 50 mA	4.814		4.886	V	
		$I_O = 1 \text{ to } 50 \text{ mA}, T_J = -40 \text{ to } 125^{\circ}\text{C}$	4.729		4.971		
		I <sub>O</sub> = 1 mA	4.975	5	5.025		
$V_{O}$	Output voltage	I <sub>O</sub> = 1 to 50 mA	4.963		5.038	V	
		$I_O = 1 \text{ to } 50 \text{ mA}, T_J = -40 \text{ to } 125^{\circ}\text{C}$	4.875		5.125		
4)/	Line regulation	$V_{O(NOM)} + 1 < V_{IN} < 16 \text{ V}, I_O = 1 \text{ mA}$		0.003	0.014	0/ /\ 1	
$\Delta V_{O}$	Line regulation	T <sub>.l</sub> = -40 to 125°C			0.032	%/V	

Table 5. Electrical characteristics for LD2980AB (continued) (T<sub>J</sub> = 25 °C, V<sub>I</sub> = V<sub>O(NOM)</sub> +1 V, C<sub>I</sub> = 1  $\mu$ F(X7R), C<sub>O</sub> = 2.2  $\mu$ F (X7R), I<sub>O</sub> = 1 mA, V<sub>INH</sub> = 2 V, unless otherwise specified).

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit	
		I <sub>O</sub> = 0		80	100		
		$I_{O} = 0$ , $T_{J} = -40$ to 125°C			150		
		I <sub>O</sub> = 1 mA		100	150		
	Quiescent current	$I_O = 1$ mA, $T_J = -40$ to $125^{\circ}$ C			200		
1.	ON MODE	I <sub>O</sub> = 10 mA		175	250		
IQ		$I_O = 10 \text{ mA}, T_J = -40 \text{ to } 125^{\circ}\text{C}$			450	μA	
		I <sub>O</sub> = 50 mA		500	700	1	
		$I_{O} = 50$ mA, $T_{J} = -40$ to $125^{\circ}$ C			1200	1	
	OFF MODE	V <sub>INH</sub> < 0.18 V		0		1	
	OFF MODE	V <sub>INH</sub> < 0.18 V, T <sub>J</sub> = -40 to 125°C			1	1	
		I <sub>O</sub> = 0		1	3		
		$I_{O} = 0$ , $T_{J} = -40$ to $125^{\circ}$ C			5	1	
		$I_O = 1mA$		7	10		
V		$I_{O} = 1 \text{mA}, T_{J} = -40 \text{ to } 125^{\circ}\text{C}$			15	m)/	
$V_{DROP}$	Dropout voltage (Note 1)	I <sub>O</sub> = 10mA		40	60	mV	
		$I_O = 10$ mA, $T_J = -40$ to $125$ °C			90	1	
		$I_O = 50 \text{mA}$		120	150	1	
		$I_O = 50$ mA, $T_J = -40$ to $125$ °C			225	1	
I <sub>SC</sub>	Short circuit current	$R_L = 0$		150		mA	
SVR	Supply voltage rejection	$C_O = 10\mu F$ , $f = 1kHz$		63		dB	
V <sub>INH</sub>	Inhibit input logic low	LOW = Output OFF, T <sub>J</sub> = -40 to 125°C		0.8	0.18	V	
V <sub>INL</sub>	Inhibit input logic high	HIGH = Output ON, T <sub>J</sub> = -40 to 125°C	1.6	1.3		V	
1	Inhibit input current	$V_{INH} = 0V, T_{J} = -40 \text{ to } 125^{\circ}C$		0	-1		
I <sub>INH</sub>	Inhibit input current	$V_{INH} = 5V$ , $T_{J} = -40$ to $125^{\circ}C$		5	15	μA	
e <sub>N</sub>	Output noise voltage	$B_W = 300 \text{ Hz to } 50 \text{ kHz}, C_O = 10 \mu\text{F}$		160		$\mu V_{RMS}$	
T <sub>SHDN</sub>	Thermal shutdown			170		°C	

Note: 1 For  $V_O < 2.5$  V dropout voltage can be calculated according to the minimum input voltage in full temperature range.

Table 6. Electrical characteristics for LD2980C ( $T_J = 25$  °C,  $V_I = V_{O(NOM)} + 1$  V,  $C_I = 1$   $\mu F$  (X7R),  $C_O = 2.2$   $\mu F$  (X7R),  $I_O = 1$  mA,  $V_{INH} = 2$  V, unless otherwise specified)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V <sub>OP</sub>	Operating input voltage		2.5		16	V
		I <sub>O</sub> = 1 mA	1.478	1.5	1.522	
$V_{O}$	Output voltage	I <sub>O</sub> = 1 to 50 mA	1.470		1.530	V
		$I_O = 1 \text{ to } 50 \text{ mA}, T_J = -40 \text{ to } 125^{\circ}\text{C}$	1.445		1.555	
		I <sub>O</sub> = 1 mA	1.782	1.8	1.818	
$V_{O}$	Output voltage	I <sub>O</sub> = 1 to 50 mA	1.773		1.827	V
		$I_O = 1 \text{ to } 50 \text{ mA}, T_J = -40 \text{ to } 125^{\circ}\text{C}$	1.737		1.863	
		I <sub>O</sub> = 1 mA	2.475	2.5	2.525	
$V_{O}$	Output voltage	I <sub>O</sub> = 1 to 50 mA	2.463		2.538	V
		$I_O = 1 \text{ to } 50 \text{ mA}, T_J = -40 \text{ to } 125^{\circ}\text{C}$	2.412		2.587	
		I <sub>O</sub> = 1 mA	2.822	2.85	2.879	
$V_{O}$	Output voltage	I <sub>O</sub> = 1 to 50 mA	2.807		2.893	V
		$I_O = 1 \text{ to } 50 \text{ mA}, T_J = -40 \text{ to } 125^{\circ}\text{C}$	2.75		2.949	
		I <sub>O</sub> = 1 mA	2.97	3	3.03	
$V_{O}$	Output voltage	I <sub>O</sub> = 1 to 50 mA	2.955		3.045	V
		$I_O = 1$ to 50 mA, $T_J = -40$ to 125°C	2.895		3.105	
		I <sub>O</sub> = 1 mA	3.168	3.2	3.232	
$V_{O}$	Output voltage	I <sub>O</sub> = 1 to 50 mA	3.152		3.248	V
		$I_O = 1$ to 50 mA, $T_J = -40$ to 125°C	3.088		3.312	
		I <sub>O</sub> = 1 mA	3.267	3.3	3.333	
$V_{O}$	Output voltage	I <sub>O</sub> = 1 to 50 mA	3.251		3.35	V
		$I_O = 1 \text{ to } 50 \text{ mA}, T_J = -40 \text{ to } 125^{\circ}\text{C}$	3.184		3.415	
		I <sub>O</sub> = 1 mA	3.564	3.6	3.636	
$V_{O}$	Output voltage	I <sub>O</sub> = 1 to 50 mA	3.546		3.654	V
		$I_O = 1$ to 50 mA, $T_J = -40$ to 125°C	3.474		3.726	
		I <sub>O</sub> = 1 mA	3.76	3.8	3.838	
$V_{O}$	Output voltage	I <sub>O</sub> = 1 to 50 mA	3.743		3.857	V
		$I_O = 1 \text{ to } 50 \text{ mA}, T_J = -40 \text{ to } 125^{\circ}\text{C}$	3.667		3.933	
		I <sub>O</sub> = 1 mA	3.96	4	4.04	
$V_{O}$	Output voltage	I <sub>O</sub> = 1 to 50 mA	3.94		4.06	V
		$I_O = 1$ to 50 mA, $T_J = -40$ to 125°C	3.86		4.14	
		I <sub>O</sub> = 1 mA	4.653	4.7	4.747	
$V_{O}$	Output voltage	I <sub>O</sub> = 1 to 50 mA	4.630		4.771	V
		$I_O = 1 \text{ to } 50 \text{ mA}, T_J = -40 \text{ to } 125^{\circ}\text{C}$	4.535		4.864	
		I <sub>O</sub> = 1 mA	4.802	4.85	4.899	
$V_{O}$	Output voltage	I <sub>O</sub> = 1 to 50 mA	4.777		4.923	٧
		$I_O = 1$ to 50 mA, $T_J = -40$ to $125^{\circ}$ C	4.68		5.02	

Table 6. Electrical characteristics for LD2980C (continued) (T<sub>J</sub> = 25 °C, V<sub>I</sub> = V<sub>O(NOM)</sub> +1 V, C<sub>I</sub> = 1  $\mu$ F (X7R), C<sub>O</sub> = 2.2  $\mu$ F (X7R), I<sub>O</sub> = 1 mA, V<sub>INH</sub> = 2 V, unless otherwise specified)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
		I <sub>O</sub> = 1 mA	4.95	5	5.05	
$V_{O}$	Output voltage	I <sub>O</sub> = 1 to 50 mA	4.925		5.075	V
		$I_O = 1 \text{ to } 50 \text{ mA}, T_J = -40 \text{ to } 125^{\circ}\text{C}$	4.825		5.175	
ΔV <sub>O</sub>	Line regulation	$V_{O(NOM)} + 1 < V_{IN} < 16 \text{ V}, I_O = 1 \text{ mA}$		0.003	0.014	%/V
ΔνΟ	Line regulation	T <sub>J</sub> = -40 to 125°C			0.032	/0/ <b>V</b>
		I <sub>O</sub> = 0		80	100	
		I <sub>O</sub> = 0, T <sub>J</sub> = -40 to 125°C			150	
		I <sub>O</sub> = 1 mA		100	150	
	Quiescent current	$I_{O} = 1$ mA, $T_{J} = -40$ to $125^{\circ}$ C			200	
1.	ON MODE	I <sub>O</sub> = 10 mA		175	250	μA
ΙQ		$I_O = 10 \text{ mA}, T_J = -40 \text{ to } 125^{\circ}\text{C}$			450	μΑ
		I <sub>O</sub> = 50 mA		500	700	
		$I_{O} = 50$ mA, $T_{J} = -40$ to $125^{\circ}$ C			1200	
	OFF MODE	V <sub>INH</sub> < 0.18 V		0		
	OIT WODE	V <sub>INH</sub> < 0.18 V, T <sub>J</sub> = -40 to 125°C			1	
		$I_{O} = 0$		1	3	
		I <sub>O</sub> = 0, T <sub>J</sub> = -40 to 125°C			5	
		$I_O = 1mA$		7	10	
V	Dropout voltage ( <i>Note 1</i> )	$I_{O} = 1$ mA, $T_{J} = -40$ to $125$ °C			15	mV
$V_{DROP}$	Diopout voltage (Note 1)	I <sub>O</sub> = 10mA		40	60	1111
		$I_{O} = 10$ mA, $T_{J} = -40$ to $125$ °C			90	
		$I_O = 50$ mA		120	150	
		$I_{O} = 50$ mA, $T_{J} = -40$ to $125$ °C			225	
I <sub>SC</sub>	Short circuit current	R <sub>L</sub> = 0		150		mA
SVR	Supply voltage rejection	$C_O = 10\mu F$ , $f = 1kHz$		63		dB
V <sub>INH</sub>	Inhibit input logic low	LOW = Output OFF, T <sub>J</sub> = -40 to 125°C		0.8	0.18	V
V <sub>INL</sub>	Inhibit input logic high	HIGH = Output ON, T <sub>J</sub> = -40 to 125°C	1.6	1.3		V
la	Inhibit input current	V <sub>INH</sub> = 0V, T <sub>J</sub> = -40 to 125°C		0	-1	μF
I <sub>INH</sub>	innibit input current	V <sub>INH</sub> = 5V, T <sub>J</sub> = -40 to 125°C		5	15	] μι
e <sub>N</sub>	Output noise voltage	$B_W = 300 \text{ Hz to } 50 \text{ kHz}, C_O = 10 \mu\text{F}$		160		$\mu V_{RMS}$
T <sub>SHDN</sub>	Thermal shutdown			170		°C

Note: 1 For  $V_O$  < 2.5 V dropout voltage can be calculated according to the minimum input voltage in full temperature range.

### **6** Typical performance characteristics

(T<sub>J</sub> = 25 °C, V<sub>I</sub> = V<sub>O(NOM)</sub> +1 V, C<sub>I</sub> = 1  $\mu$ F (X7R), C<sub>O</sub> = 2.2  $\mu$ F (X7R), V<sub>INH</sub> = 2 V, unless otherwise specified)

Figure 4. Output voltage vs temperature

Figure 5. Output voltage vs temperature

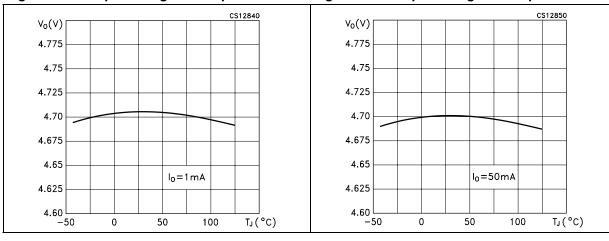


Figure 6. Line regulation vs temperature

Figure 7. Load regulation vs temperature

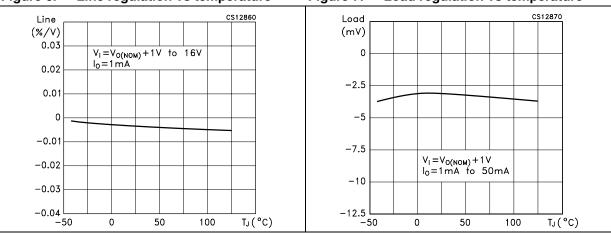


Figure 8. Dropout voltage vs temperature

Figure 9. Quiescent current vs temperature

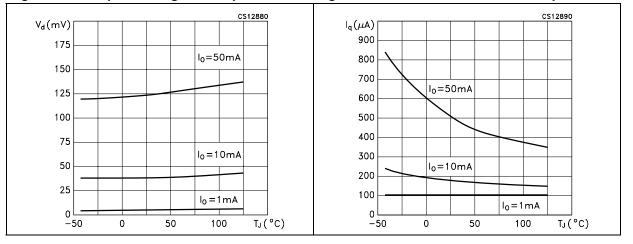
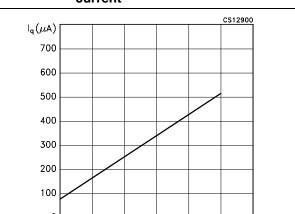


Figure 10. Quiescent current vs output current



30

40

50

 $l_0(mA)$ 

Figure 11. Off mode quiescent current vs temperature

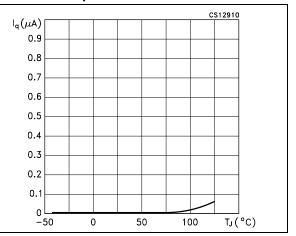
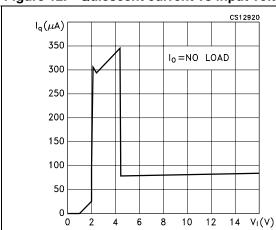


Figure 12. Quiescent current vs input voltage Figure 13. Dropout voltage vs output current



10

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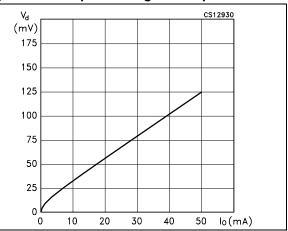
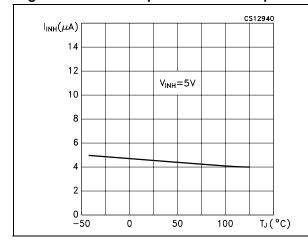


Figure 14. Inhibit input current vs temperature Figure 15. Inhibit voltage vs temperature



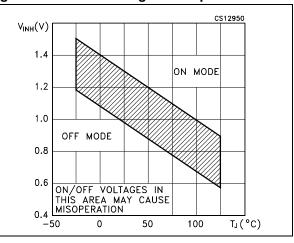
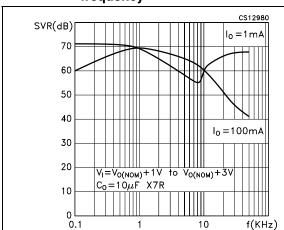


Figure 16. Supply voltage rejection vs frequency

Figure 17. Noise voltage vs frequency



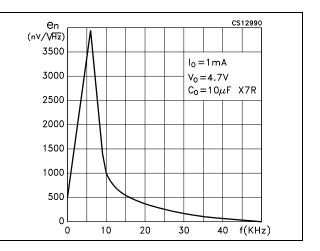
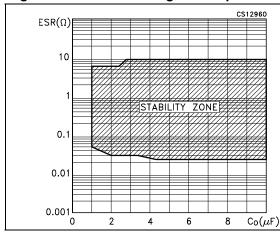


Figure 18. Best case: highest output version

Figure 19. Worst case: lowest output version



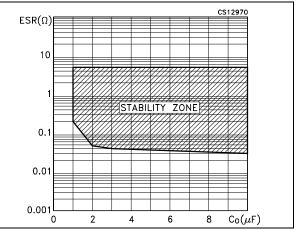
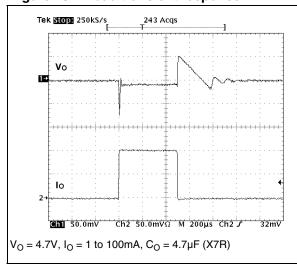
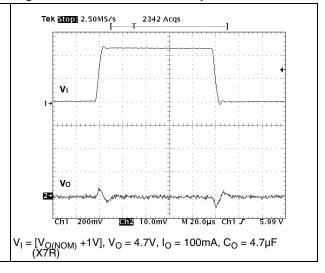


Figure 20. Load transient response

Figure 21. Line transient response





### 7 Application notes

#### 7.1 External capacitors

Like any low-dropout regulator, the LD2980 requires external capacitors for regulator stability. This capacitor must be selected to meet the requirements of minimum capacitance and equivalent series resistance. We suggest to solder input and output capacitors as close as possible to the relative pins.

#### 7.2 Input capacitor

An input capacitor whose value is 1  $\mu$ F is required with the LD2980 (amount of capacitance can be increased without limit). This capacitor must be located a distance of not more than 0.5" from the input pin of the device and returned to a clean analog ground. Any good quality ceramic, tantalum or film capacitors can be used for this capacitor.

#### 7.3 Output capacitor

The LD2980 is designed specifically to work with ceramic output capacitors. It may also be possible to use Tantalum capacitors, but these are not as attractive for reasons of size and cost. By the way, the output capacitor must meet both the requirement for minimum amount of capacitance and ESR (equivalent series resistance) value. The *Figure 4* and *Figure 5* show the allowable ESR range as a function of the output capacitance. These curves represent the stability region over the full temperature and  $I_O$  range. Due to the different loop gain, the stability improves for higher output versions and so the suggested minimum output capacitor value, if low ESR ceramic type is used, is 1  $\mu$ F for output voltages equal or major than 3.8 V, 2.2  $\mu$ F for output voltages from 2.85 to 3.3 V, and 3.3  $\mu$ F for the other versions. However, if an output capacitor lower than the suggested one is used, it's possible to make stable the regulator adding a resistor in series to the capacitor (see *Figure 1 & Figure 2* to choose the right value according to the used version and keeping in account that the ESR of ceramic capacitors has been measured @ 100 kHz).

#### 7.4 Important

The output capacitor must maintain its ESR in the stable region over the full operating temperature to assure stability. Also, capacitor tolerance and variation with temperature must be considered to assure the minimum amount of capacitance is provided at all times. This capacitor should be located not more than 0.5" from the output pin of the device and returned to a clean analog ground.

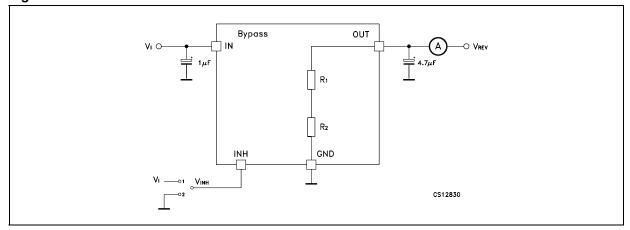
#### 7.5 Inhibit input operation

The inhibit pin can be used to turn OFF the regulator when pulled low, so drastically reducing the current consumption down to less than 1  $\mu A.$  When the inhibit feature is not used, this pin must be tied to  $V_I$  to keep the regulator output ON at all times. To assure proper operation, the signal source used to drive the inhibit pin must be able to swing above and below the specified thresholds listed in the electrical characteristics section under  $V_{IH}$   $V_{IL}.$  Any slew rate can be used to drive the inhibit.

#### 7.6 Reverse current

The power transistor used in the LD2980 has not an inherent diode connected between the regulator input and output. If the output is forced above the input, no current will flow from the output to the input across the series pass transistor. When a  $V_{REV}$  voltage is applied on the output, the reverse current measured, according to the test circuit in *Figure 22*, flows to the GND across the two feedback resistors. This current typical value is 160  $\mu$ A.  $R_1$  and  $R_2$  resistors are implanted type; typical values are, respectively, 42.6  $k\Omega$  and 51.150  $k\Omega$ 

Figure 22. Reverse current test circuit

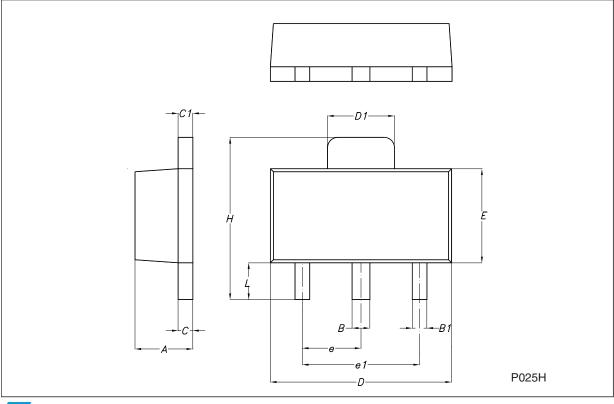


### 8 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second Level Interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

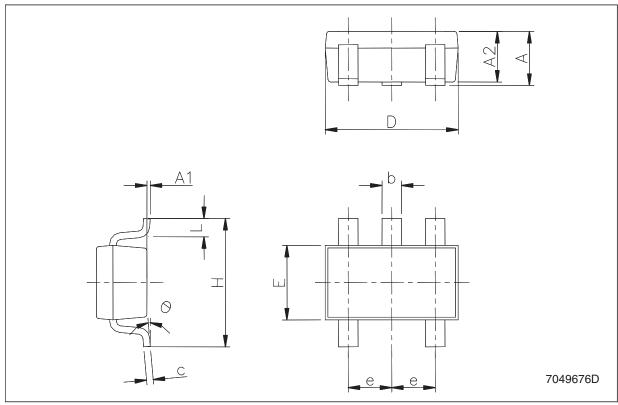
#### SOT-89 mechanical data

Dim		mm.			mils.	
Dim.	Min.	Тур.	Max.	Min.	Тур.	Max.
А	1.4		1.6	55.1		63.0
В	0.44		0.56	17.3		22.0
B1	0.36		0.48	14.2		18.9
С	0.35		0.44	13.8		17.3
C1	0.35		0.44	13.8		17.3
D	4.4		4.6	173.2		181.1
D1	1.62		1.83	63.8		72.0
E	2.29		2.6	90.2		102.4
е	1.42		1.57	55.9		61.8
e1	2.92		3.07	115.0		120.9
Н	3.94		4.25	155.1		167.3
L	0.89		1.2	35.0		47.2



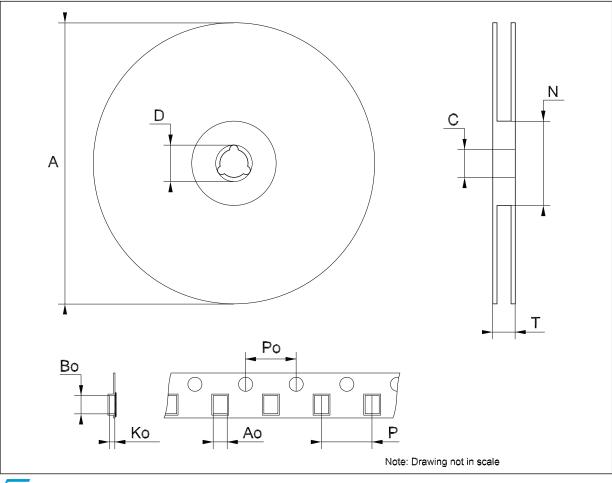
#### SOT23-5L mechanical data

Dim		mm.				
Dim.	Min.	Тур.	Max.	Min.	Тур.	Max.
А	0.90		1.45	35.4		57.1
A1	0.00		0.10	0.0		3.9
A2	0.90		1.30	35.4		51.2
b	0.35		0.50	13.7		19.7
С	0.09		0.20	3.5		7.8
D	2.80		3.00	110.2		118.1
E	1.50		1.75	59.0		68.8
е		0.95			37.4	
Н	2.60		3.00	102.3		118.1
L	0.10		0.60	3.9		23.6



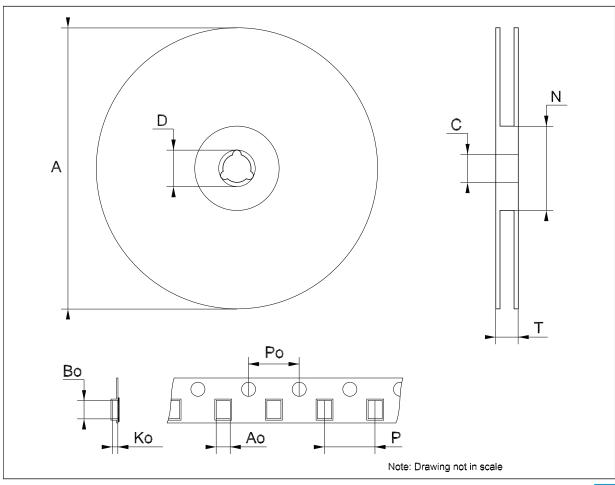
Tape & reel SOT23-xL mechanical data

Dim		mm.			inch.		
Dim.	Min.	Тур.	Max.	Min.	Тур.	Max.	
А			180			7.086	
С	12.8	13.0	13.2	0.504	0.512	0.519	
D	20.2			0.795			
N	60			2.362			
Т			14.4			0.567	
Ao	3.13	3.23	3.33	0.123	0.127	0.131	
Во	3.07	3.17	3.27	0.120	0.124	0.128	
Ko	1.27	1.37	1.47	0.050	0.054	0.0.58	
Po	3.9	4.0	4.1	0.153	0.157	0.161	
Р	3.9	4.0	4.1	0.153	0.157	0.161	



Tape & reel SOT89 mechanical data

Dim.	mm.			inch.		
	Min.	Тур.	Max.	Min.	Тур.	Max.
А			180			7.086
С	12.8	13.0	13.2	0.504	0.512	0.519
D	20.2			0.795		
N	60			2.362		
Т			14.4			0.567
Ao	4.70	4.80	4.90	0.185	0.189	0.193
Во	4.30	4.40	4.50	0.169	0.173	0.177
Ko	1.70	1.80	1.90	0.067	0.071	0.075
Po	3.9	4.0	4.1	0.153	0.157	0.161
Р	7.9	8.0	8.1	0.311	0.315	0.319



## 9 Revision history

Table 7. Document revision history

Date	Revision	Changes	
03-Jul-2006	13	Order codes updated and new template.	
13-Nov-2006	14	Add part number LD2980ABU18TR.	
06-Sep-2007	15	Add Table 1 on page 1.	
14-Feb-2008	16	Modified: Table 1 on page 1.	

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